RENESAS

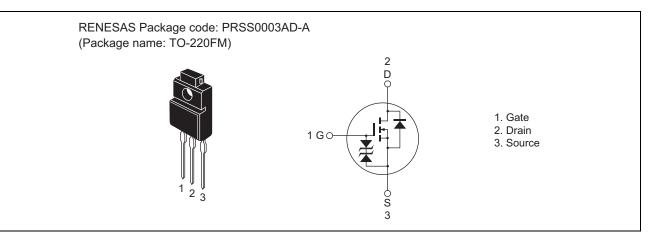
60 V - 30 A - N Channel Power MOS FET High Speed Power Switching

R07DS0879EJ0200 Rev.2.00 May 23, 2013

Features

- For Automotive application
- AEC-Q101 compliant
- Low on-resistance : $R_{DS(on)} = 12 \text{ m}\Omega \text{ typ.}$
- Capable of 4.5 V gate drive
- Low input capacitance: Ciss = 1350 pF typ

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	ID	30	А
Drain peak current	I _D (pulse) Note1	120	А
Body-drain diode reverse drain current	I _{DR}	30	А
Body-drain diode reverse drain peak current	I _{DR} (pulse) Note1	120	А
Avalanche current	I _{AP} Note2	27	А
Avalanche energy	E _{AR} Note2	62.5	mJ
Channel dissipation	Pch Note3	30	W
Channel temperature	Tch Note4	175	٥°
Storage temperature	Tstg	-55 to +150	۵°

Notes: 1. $PW \le 10\mu s \text{ duty cycle} \le 1\%$

- 2. Tch = 25°C, Rg \geq 50 Ω
- 3. Tc = 25°C
- 4. AEC-Q101 compliant

Thermal Impedance Characteristics

• Channel to case thermal impedance θ ch-c: 5.00°C/W



 $(T_{0} - 25^{\circ}C)$

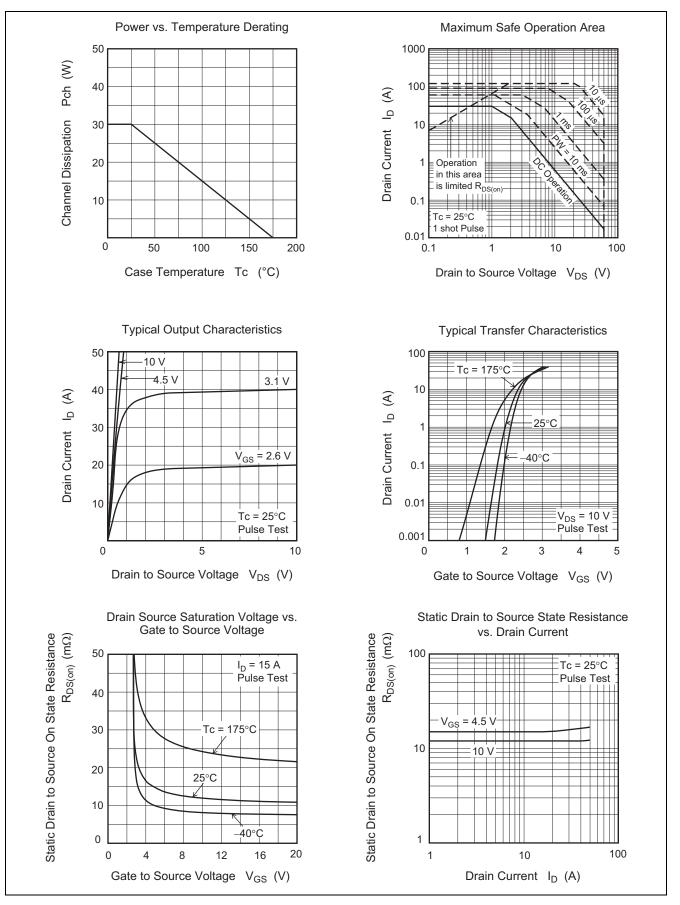
Electrical Characteristics

						(Ta = 25°	
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Gate to source leak current	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0$	
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0$	
Gate to source cutoff voltage	V _{GS(off)}	1.0	_	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$	
Static drain to source on state	R _{DS(on)}		12	15	mΩ	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$	
resistance			15	20	mΩ	$I_D = 15 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note5}}$	
Input capacitance	Ciss	_	1350		pF	$V_{DS} = 10V, V_{GS} = 0,$ f = 1 MHz	
Output capacitance	Coss	_	360	—	pF		
Reverse transfer capacitance	Crss	_	270		pF		
Total gate charge	Qg		32		nC	$V_{DD} = 25 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$ $I_D = 30 \text{ A}$	
Gate to source charge	Qgs		3.6		nC		
Gate to drain charge	Qgd		10	_	nC		
Turn-on delay time	t _{d(on)}		13		ns	I_D = 15 A, R _L = 2 Ω, V _{GS} = 10 V, R _G = 4.7 Ω	
Rise time	tr		15		ns		
Turn-off delay time	t _{d(off)}	_	60	—	ns		
Fall time	t _f	_	15	—	ns		
Body-drain diode forward voltage	V _{DF}		0.94	1.17	V	$I_F = 30 \text{ A}, V_{GS} = 0^{\text{Note5}}$	
Body-drain diode reverse recovery	t _{rr}	_	40	—	ns	$I_F = 30 \text{ A}, V_{GS} = 0$	
time						di _F /dt = 100 A/µs	

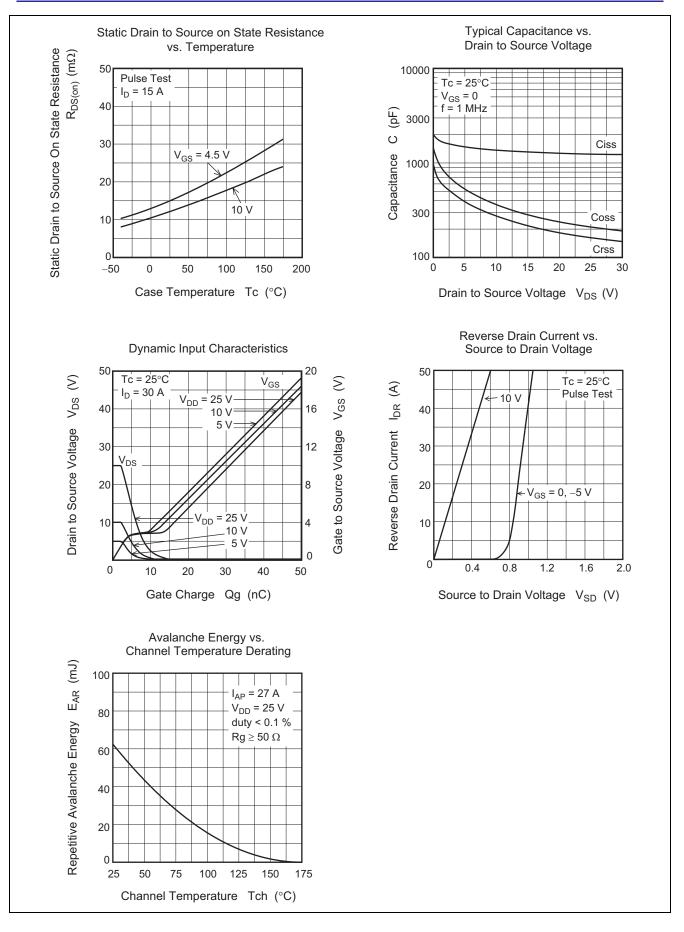
Note: 5. Pulse test



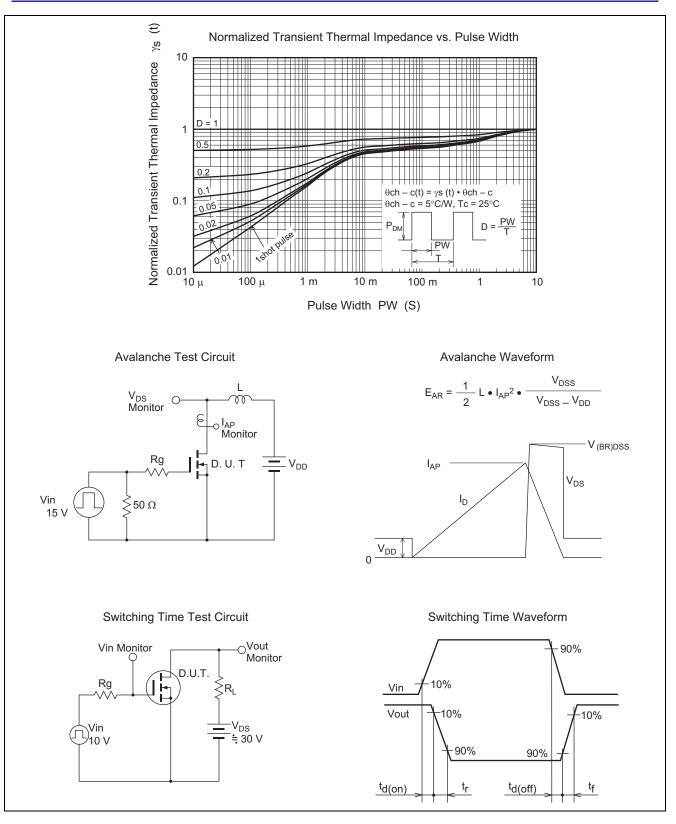
Main Characteristics





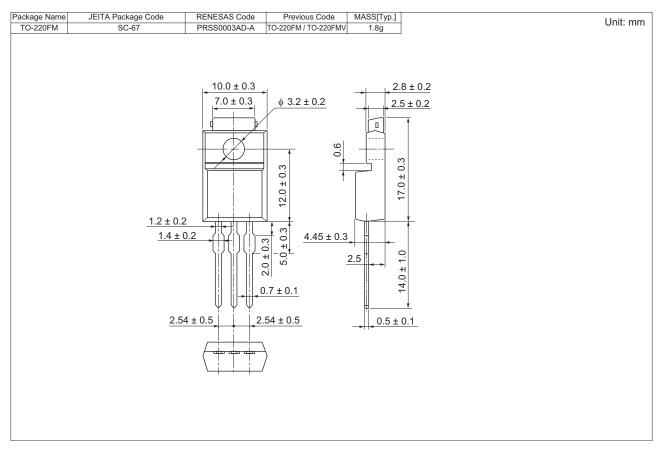








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK0631JPR-00-T2	600 pcs	Box (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".



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